NPN Triple Diffused Planar Silicon Transistor



2SC4461

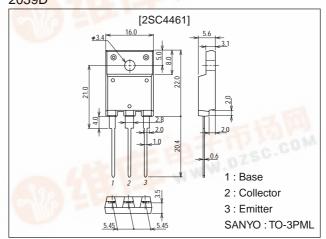
500V/25A Switching Regulator Applications

Features

- · High breakdown voltage, high reliability.
- · Fast switching speed.
- · Wide ASO.
- · Adoption of MBIT process.
- · Micaless package facilitating mounting.

Package Dimensions

unit:mm 2039D



Specifications

Absolute Maximum Ratings at Ta = 25°C

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	V _{CBO}		800	V
Collector-to-Emitter Voltage	V _{CEO}		500	V
Emitter-to-Base Voltage	V _{EBO}	100	7	V
Collector Current	I _C	The second secon	25	А
Collector Current (Pulse)	I _{CP}	PW≤300μs, duty cycle≤10%	40	А
Base Current	IB	AREA 1815	8	А
Collector Dissipation	PC	189 14 - 5	3	W
		Tc=25°C	65	W
Junction Temperature	Tj	10 100	150	°C
Storage Temperature	Tstg	- Com	-55 to +150	°C

Electrical Characteristics at Ta = 25°C

Parameter	Symbol	Conditions		Ratings		
	Symbol			typ	max	Unit
Collector Cutoff Current	I _{CBO}	V _{CB} =500V, I _E =0			10	μΑ
Emitter Cutoff Current	I _{EBO}	V _{EB} =5V, I _C =0	- 42-		10	μA
DC Current Gain	h _{FE} 1	V _{CE} =5V, I _C =2.4A	15*	M D	50*	art or
	h _{FF} 2	V _{CF} =5V, I _C =12A	8			

*: For the h_{FE}1 of the 2SC4461, specify two ranks or more in principle.

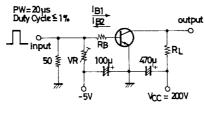
15	L	30	20	M	40	30	Ν	50

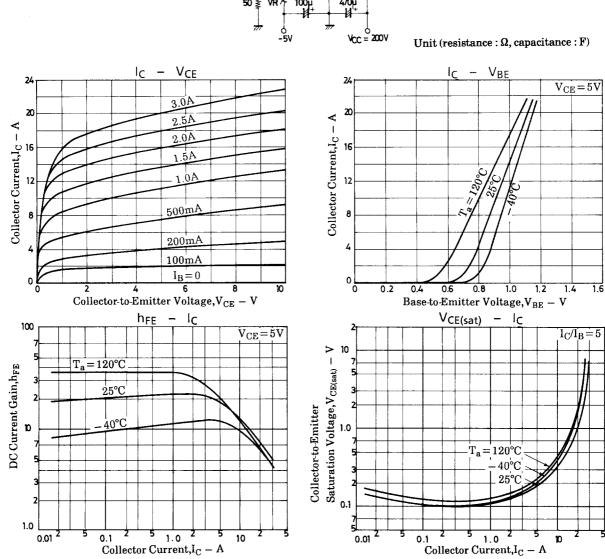
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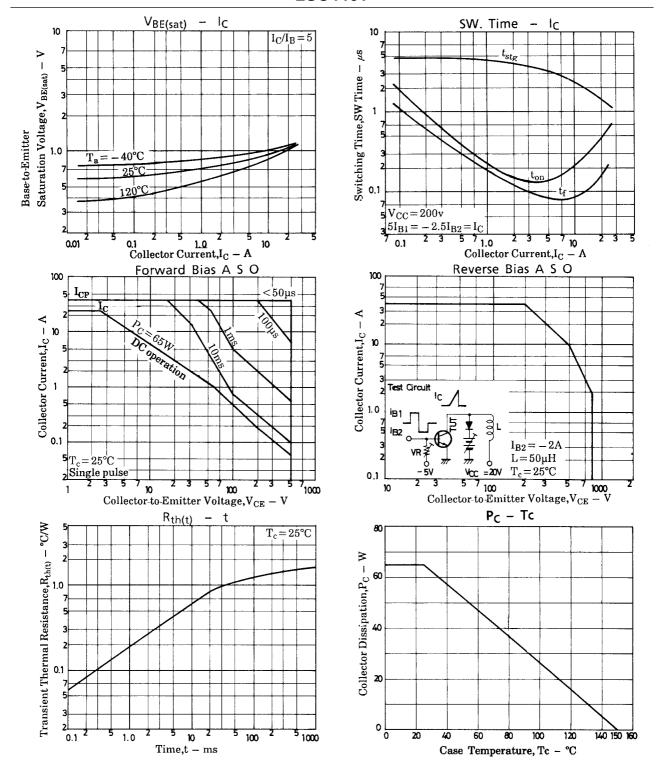
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Parameter	Symbol	Conditions		Unit		
Farameter	Symbol	Conditions	min	typ	max	Offic
Gain-Bandwidth Product	fT	V _{CE} =10V, I _C =2.4A		18		MHz
Output Capacitance	C _{ob}	V _{CB} =10V, f=1MHz		260		pF
Collector-to-Emitter Saturation Voltage	VCE(sat)	I _C =12A, I _B =2.4A			1.0	V
Base-to-Emitter Saturation Voltage	V _{BE(sat)}	I _C =12A, I _B =2.4A			1.5	V
Collector-to-Base Breakdown Voltage	V _(BR) CBO	I _C =1mA, I _E =0	800			V
Collector-to-Emitter Breakdown Voltage	V(BR)CEO	I _C =5mA, R _{BE} =∞	500			V
Emitter-to-Base Breakdown Voltage	V(BR)EBO	I _E =1mA, I _C =0	7			V
Collector-to-Emitter Sustain Voltage	V _{CEX(sus)}	I _C =10A, I _{B1} =-I _{B2} =2A, L=200μH, Clamped	500			V
Turn-ON Time	ton	V_{CC} =200V, $5I_{B1}$ =-2. $5I_{B2}$ = I_{C} =14A, R_{L} =14. 3Ω			0.5	μs
Storage Time	t _{stg}	V_{CC} =200V, $5I_{B1}$ =-2.5 I_{B2} = I_{C} =14A, R_{L} =14.3 Ω			3.0	μs
Fall Time	t _f	V _{CC} =200V, 5l _{B1} =-2.5l _{B2} =l _C =14A, R _L =14.3Ω			0.3	μs

Switching Time Test Circuit







2SC4461

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